

## NCE N-Channel Enhancement Mode Power MOSFET

## **Description**

The NCE3400E uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application. It is ESD protested.

### **General Features**

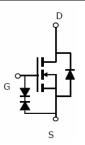
•  $V_{DS} = 30V, I_D = 5.3A$ 

 $R_{DS(ON)}$  < 57m $\Omega$  @  $V_{GS}$ =2.5V

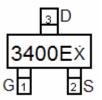
 $R_{DS(ON)}$  < 40m $\Omega$  @  $V_{GS}$ =4.5V

 $R_{DS(ON)}$  < 33m $\Omega$  @  $V_{GS}$ =10V

- High power and current handing capability
- Lead free product is acquired
- Surface mount package
- PWM applications
- Load switch
- Power management



Schematic diagram



Marking and pin assignment



SOT-23 top view

## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3400E X	NCE3400E	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V <sub>DS</sub>	30	V	
Gate-Source Voltage	V <sub>GS</sub>	±12	V	
Drain Current-Continuous	I <sub>D</sub>	5.3	Α	
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	22	Α	
Maximum Power Dissipation	P <sub>D</sub>	1.4	W	
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	$^{\circ}$	

### **Thermal Characteristic**

## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	30	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V	-	-	1	μΑ



# http://www.ncepower.com

# NCE3400E

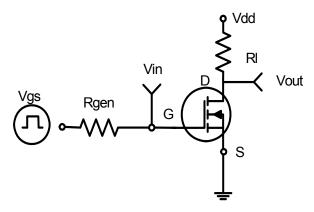
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm 10V, V_{DS}=0V$	-	-	±10	μΑ
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS},I_{D}=250\mu A$	0.6	0.9	1.2	V
ain-Source On-State Resistance		V <sub>GS</sub> =2.5V, I <sub>D</sub> =4A	-	27	57	mΩ
	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =5A	-	23	40	mΩ
		V <sub>GS</sub> =10V, I <sub>D</sub> =5.3A	-	21	33	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =5A	10	-	-	S
Dynamic Characteristics (Note4)	·					
Input Capacitance	C <sub>lss</sub>	\\	-	597	-	PF
Output Capacitance	Coss	$V_{DS}$ =15V, $V_{GS}$ =0V, F=1.0MHz	-	66.4	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0WHZ	-	58.8	-	PF
Switching Characteristics (Note 4)	·					
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =15V, R <sub>L</sub> =2.8Ω	-	3	-	nS
Turn-on Rise Time	t <sub>r</sub>		-	2.8	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{GEN}$ =3 $\Omega$	-	25	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	4	-	nS
Total Gate Charge	Qg	\/ 45\/\ 5.0A	-	9.1	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =15V, $I_{D}$ =5.3A, $V_{GS}$ =4.5V	-	2.1	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> -4.5V	-	2.8	-	nC
Drain-Source Diode Characteristics			•	•	-	
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =5.3A	-	-	1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	5.3	Α

#### Notes

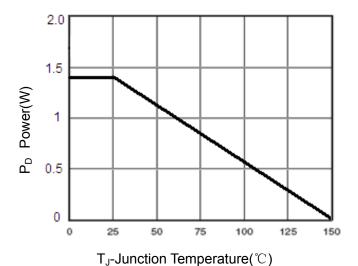
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤  $300\mu$ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



# **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Power Dissipation** 

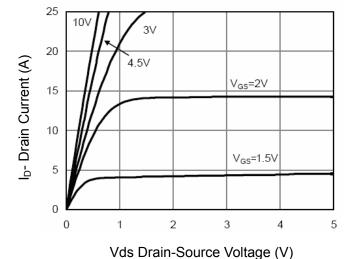


Figure 5 Output Characteristics

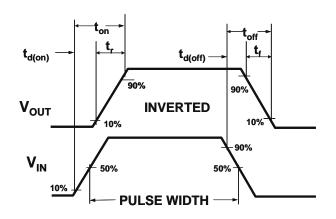
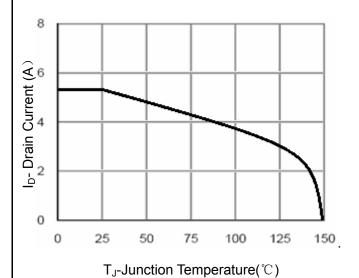


Figure 2:Switching Waveforms



**Figure 4 Drain Current** 

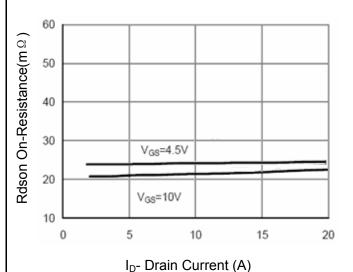
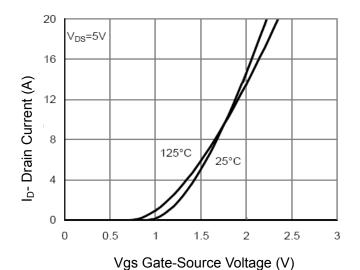
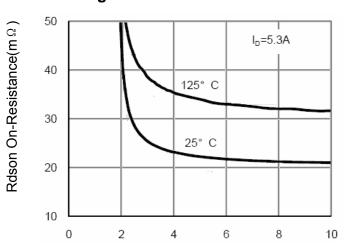


Figure 6 Drain-Source On-Resistance





**Figure 7 Transfer Characteristics** 



Vgs Gate-Source Voltage (V)
Figure 9 Rdson vs Vgs

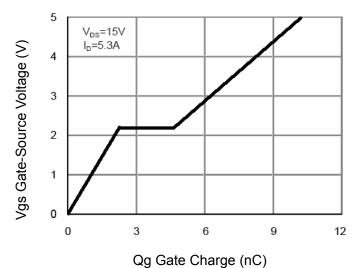


Figure 11 Gate Charge

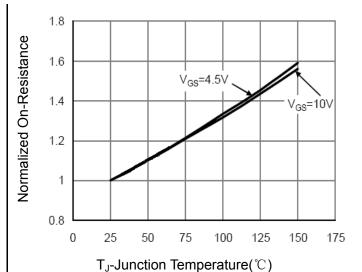


Figure 8 Drain-Source On-Resistance

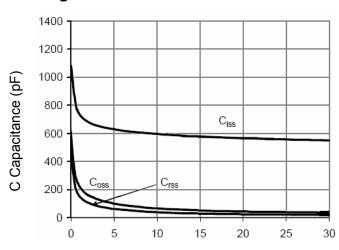


Figure 10 Capacitance vs Vds

Vds Drain-Source Voltage (V)

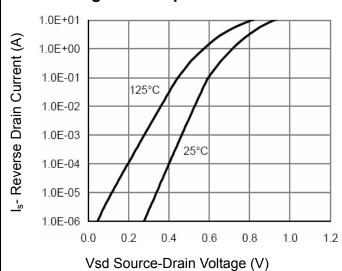
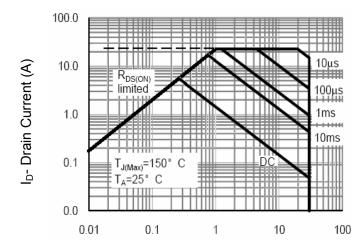


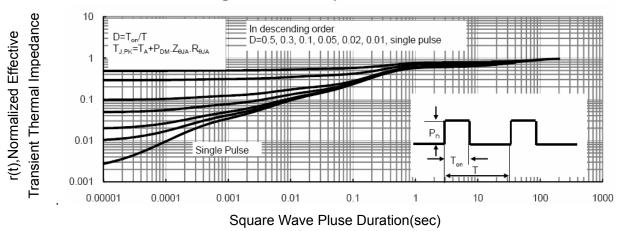
Figure 12 Source- Drain Diode Forward





Vds Drain-Source Voltage (V)

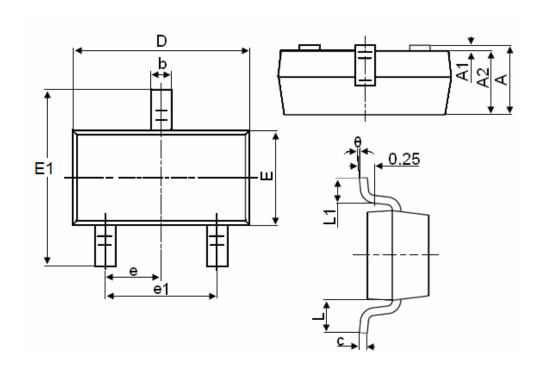
Figure 13 Safe Operation Area



**Figure 14 Normalized Maximum Transient Thermal Impedance** 



# **SOT-23 Package Information**



Cumbal	Dimensions in Millimeters				
Symbol	MIN.	MAX.			
А	0.900	1.150			
A1	0.000	0.100			
A2	0.900	1.050			
b	0.300	0.500			
С	0.080	0.150			
D	2.800	3.000			
E	1.200	1.400			
E1	2.250	2.550			
е		0.950TYP			
e1	1.800	2.000			
L		0.550REF			
L1	0.300	0.500			
θ	0°	8°			

## **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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